

# Sishir Bhowmick

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/10568892/publications.pdf>

Version: 2024-02-01

11

papers

230

citations

1478505

6

h-index

1588992

8

g-index

11

all docs

11

docs citations

11

times ranked

370

citing authors

#	ARTICLE		IF	CITATIONS
1	Solid State Electrically Injected Exciton-Polariton Laser. <i>Physical Review Letters</i> , 2013, 110, 206403.		7.8	159
2	Quantum dot rolled-up microtube optoelectronic integrated circuit. <i>Optics Letters</i> , 2013, 38, 1685.		3.3	11
3	Polariton emission characteristics of a modulation-doped multiquantum-well microcavity diode. <i>Applied Physics Letters</i> , 2012, 101, 131112.		3.3	5
4	A quantum dot rolled-up microtube directional coupler. <i>Applied Physics Letters</i> , 2012, 101, .		3.3	15
5	Threshold Characteristics of Quantum Dot Rolled-Up Microtube Lasers. <i>IEEE Journal of Quantum Electronics</i> , 2012, 48, 927-933.		1.9	13
6	Effect of magnetic field on polariton emission characteristics of a quantum-well microcavity diode. <i>Applied Physics Letters</i> , 2012, 100, 171106.		3.3	4
7	Effects of source-drain underlaps on the performance of silicon nanowire on insulator transistors. <i>Nano-Micro Letters</i> , 2010, 2, 83-88.		27.0	8
8	Cross-sectional shape effects on the electronic properties of Silicon nanowires. , 2008, , .			2
9	The effects of doping, gate length, and gate dielectric on inverse subthreshold slope and on/off current ratio of a top gate silicon nanowire transistor. , 2008, , .			1
10	Dielectric scaling of a top gate silicon nanowire on insulator transistor. <i>Journal of Applied Physics</i> , 2008, 104, .		2.5	12
11	Effects of gate length on the performance of a top gate silicon nanowire on insulator (SOI) transistor. , 2008, , .			0